

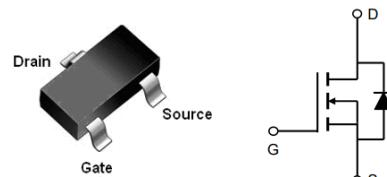
## Features

- Low R<sub>DSON</sub> @ VGS=10V
- 5V Logic Level Control
- N Channel SOT23 Package
- HMB ESD Protection
- Pb-Free, RoHS Compliant

V <sub>(BR)DSS</sub>	R <sub>DSON</sub> Typ	I <sub>D</sub> Max
100V	3.5Ω @ 10V	0.2A
	4Ω @ 4.5V	

## Applications

- Relay Driver
- ON/OFF Switch
- High-speed line Driver
- Power Management in Portable and Battery etc.



**SOT23**

## Order Information

Product	Package	Marking	Packing	Min Unit Quantity
BSS123	SOT23	SAs	3000PCS/Reel	3000PCS

## Absolute Maximum Ratings

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Symbol	Parameter	Rating	Unit
<b>Common Ratings (TA=25°C Unless Otherwise Noted)</b>			
V <sub>GS</sub>	Gate-Source Voltage	±20	V
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	100	V
T <sub>J</sub>	Maximum Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature Range	-50 to 150	°C
Mounted on Large Heat Sink			
I <sub>DM</sub>	Pulse Drain Current Tested①	T <sub>A</sub> =25°C	A
I <sub>D</sub>	Continuous Drain Current	T <sub>A</sub> =25°C	0.2
		T <sub>A</sub> =70°C	0.15
P <sub>D</sub>	Maximum Power Dissipation	T <sub>A</sub> =25°C	0.3
		T <sub>A</sub> =70°C	0.2
R <sub>θJA</sub>	Thermal Resistance Junction-Ambient	400	°C/W



Symbol	Parameter	Condition	Min	Typ	Max	Unit
<b>Static Electrical Characteristics @ <math>T_J = 25^\circ C</math> (unless otherwise stated)</b>						
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	$V_{GS}=0V, I_D=250\mu A$	100	--	--	V
$I_{DSS}$	Zero Gate Voltage Drain Current( $T_A=25^\circ C$ )	$V_{DS}=100V, V_{GS}=0V$	--	--	1	$\mu A$
	Zero Gate Voltage Drain Current( $T_A=125^\circ C$ )	$V_{DS}=80V, V_{GS}=0V$	--	--	100	$\mu A$
$I_{GSS}$	Gate-Body Leakage Current	$V_{GS}=\pm 20V, V_{DS}=0V$	--	--	$\pm 10$	$\mu A$
$V_{GS(TH)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_D=250\mu A$	1.0	2.0	3.0	V
$R_{DS(ON)}$	Drain-Source On-State Resistance②	$V_{GS}=10V, I_D=0.2A$	--	3.5	6	$\Omega$
$R_{DS(ON)}$	Drain-Source On-State Resistance②	$V_{GS}=4.5V, I_D=0.1A$	--	4	8	$\Omega$
<b>Dynamic Electrical Characteristics @ <math>T_J = 25^\circ C</math> (unless otherwise stated)</b>						
$C_{iss}$	Input Capacitance	$V_{DS}=50V, V_{GS}=0V, f=1MHz$	--	31.6	--	pF
$C_{oss}$	Output Capacitance		--	2.8	--	pF
$C_{rss}$	Reverse Transfer Capacitance		--	2	--	pF
$Q_g$	Total Gate Charge	$V_{DS}=50V$ $I_D=0.2A,$ $V_{GS}=10V$	--	0.74	--	nC
$Q_{gs}$	Gate Source Charge		--	0.08	--	nC
$Q_{gd}$	Gate Drain Charge		--	0.26	--	nC
<b>Switching Characteristics @ <math>T_J = 25^\circ C</math> (unless otherwise stated)</b>						
$t_{d(on)}$	Turn on Delay Time	$V_{DD}=50V,$ $I_D=0.2A,$ $R_G=3.3\Omega,$ $V_{GS}=10V$	--	2	--	ns
$t_r$	Turn on Rise Time		--	3.1	--	ns
$t_{d(off)}$	Turn Off Delay Time		-	6.5	--	ns
$t_f$	Turn Off Fall Time		--	15	--	ns
<b>Source Drain Diode Characteristics @ <math>T_J = 25^\circ C</math> (unless otherwise stated)</b>						
$I_{SD}$	Source drain current(Body Diode)	$T_A=25^\circ C$	--	--	0.1	A
$V_{SD}$	Forward on voltage②	$T_J=25^\circ C, I_{SD}=0.2A,$ $V_{GS}=0V$	--	0.85	1.2	V

Notes:

① Pulse width limited by maximum allowable junction temperature

②Pulse test ; Pulse width $\leq 300\mu s$ , duty cycle 2%.

## Typical Characteristics

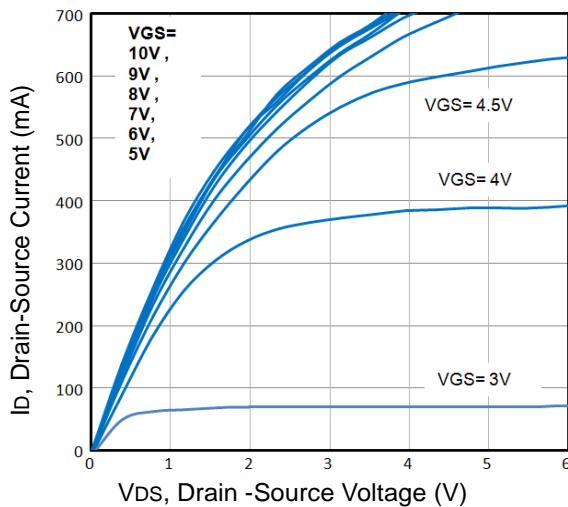


Fig1. Typical Output Characteristics

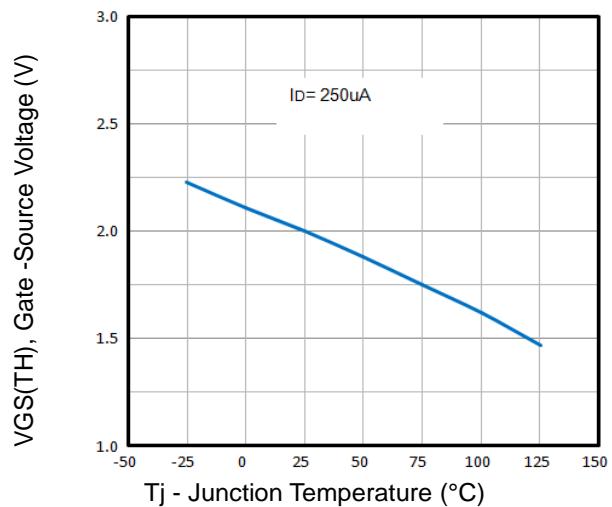


Fig2. Normalized Threshold Voltage Vs. Temperature

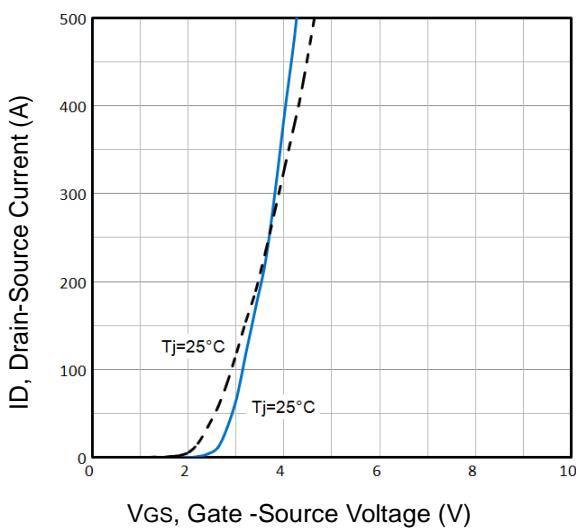


Fig3. Typical Transfer Characteristics

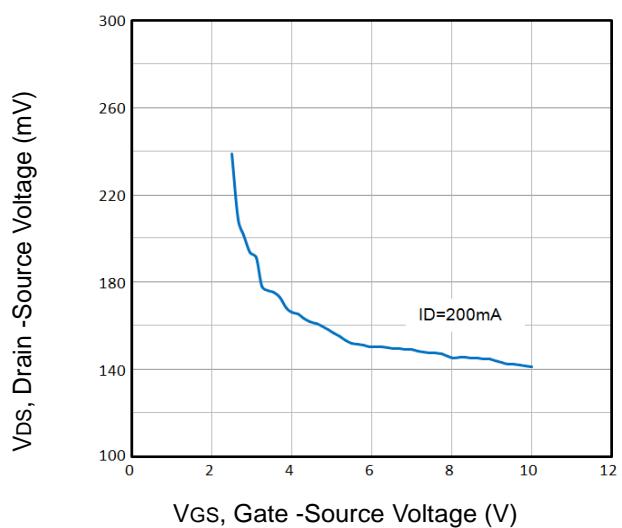


Fig4. Drain -Source Voltage vs Gate -Source Voltage

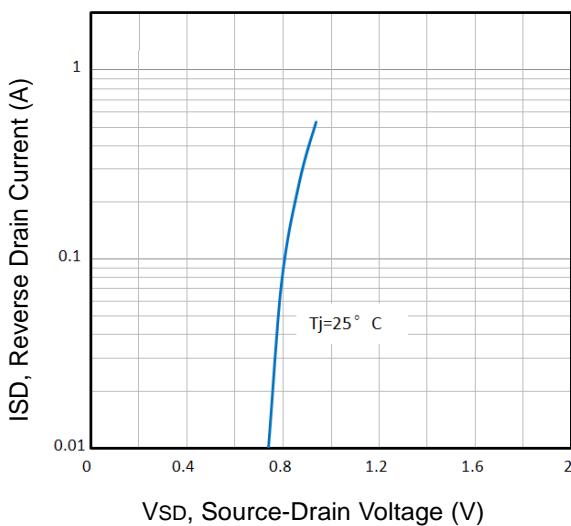


Fig5. Typical Source-Drain Diode Forward Voltage

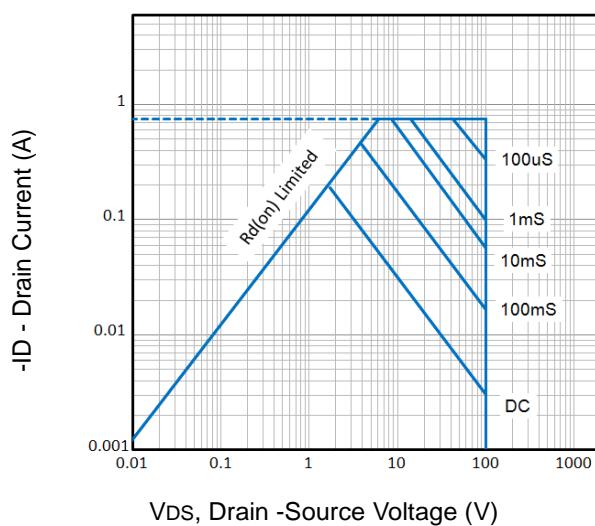
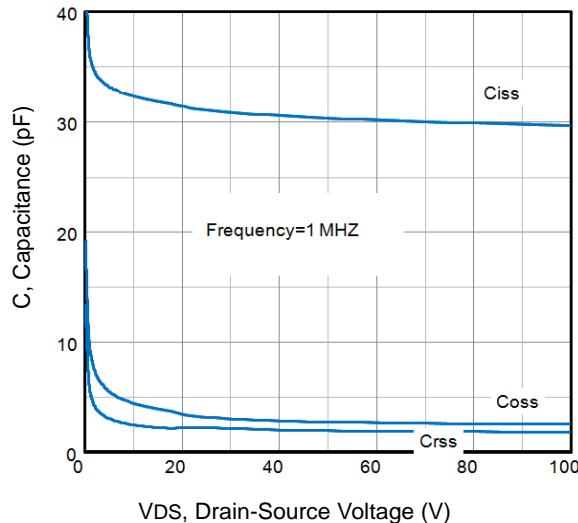
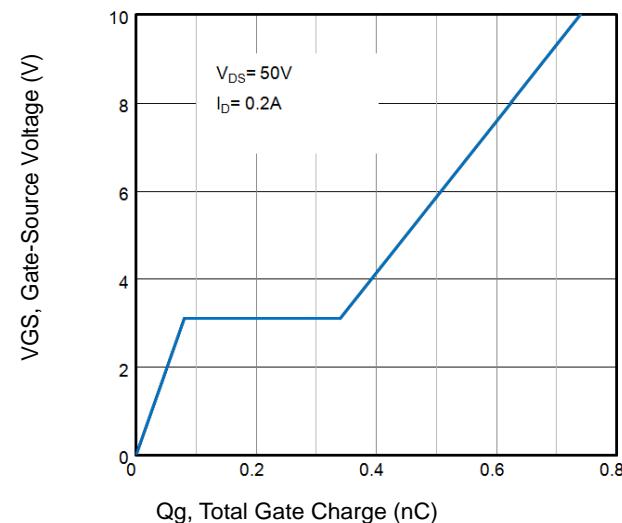


Fig6. Maximum Safe Operating Area

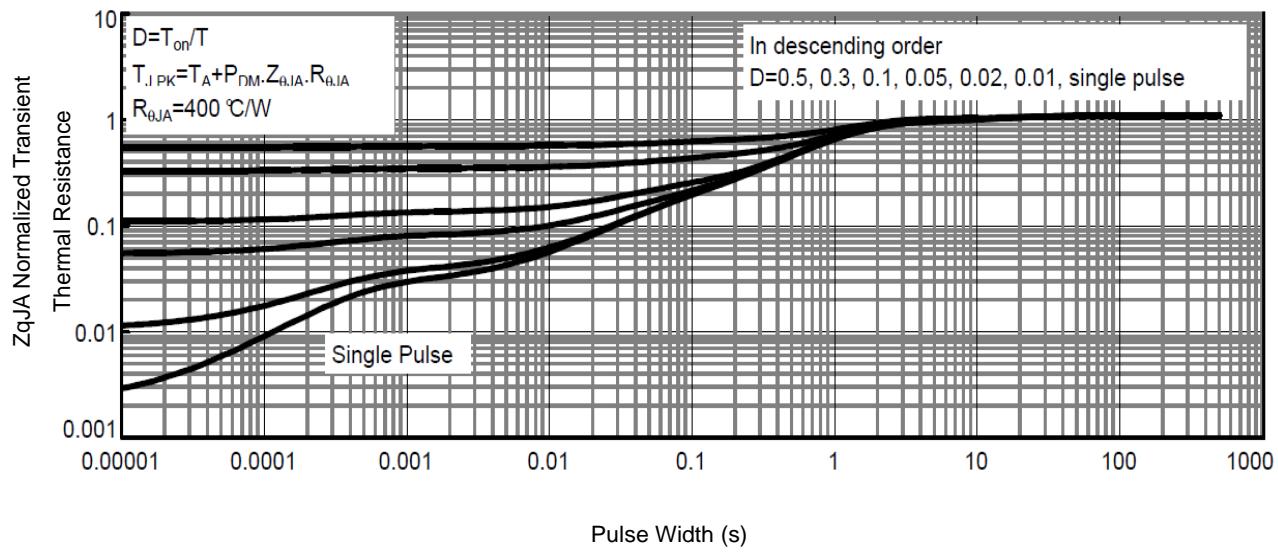
## Typical Characteristics



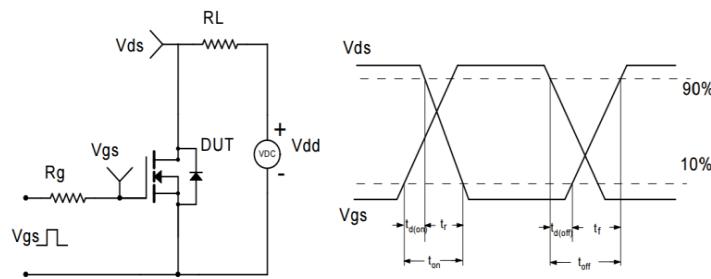
**Fig7.** Typical Capacitance Vs. Drain-Source Voltage



**Fig8.** Typical Gate Charge Vs. Gate-Source Voltage

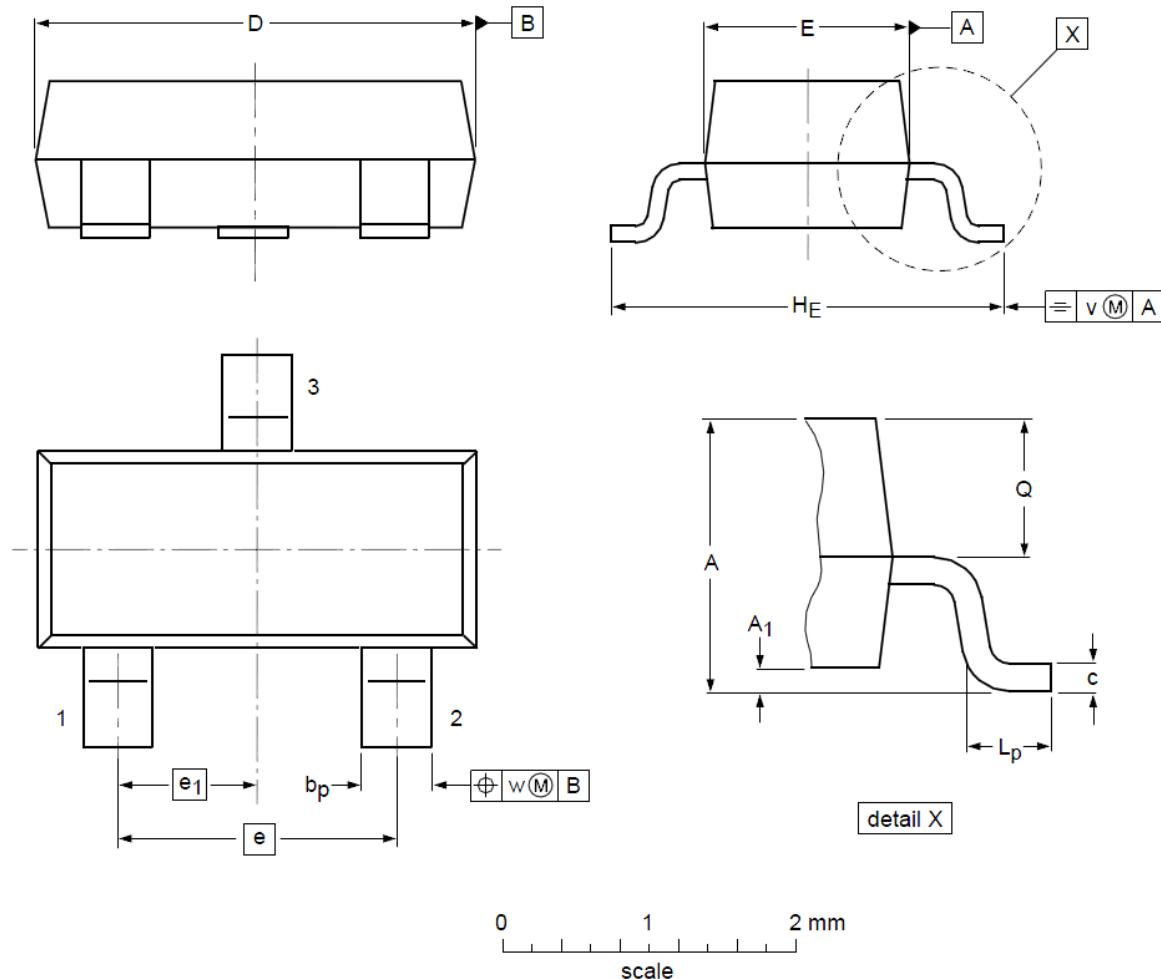


**Fig9.** Normalized Maximum Transient Thermal Impedance



**Fig10.** Switching Time Test Circuit and waveforms

## SOT23 Mechanical Data



### DIMENSIONS (unit : mm)

Symbol	Min	Typ	Max	Symbol	Min	Typ	Max
A	0.90	1.01	1.15	A <sub>1</sub>	0.01	0.05	0.10
b <sub>p</sub>	0.30	0.42	0.50	c	0.08	0.13	0.15
D	2.80	2.92	3.00	E	1.20	1.33	1.40
e	--	1.90	--	e <sub>1</sub>	--	0.95	--
H <sub>E</sub>	2.25	2.40	2.55	L <sub>p</sub>	0.30	0.42	0.50
Q	0.45	0.49	0.55	v	--	0.20	--
w	--	0.10	--				